SN74CB3T3257 4-BIT 1-OF-2 FET MULTIPLEXER/DEMULTIPLEXER

STRUMENTS .5-V/3.3-V LOW-VOLTAGE BUS SWITCH WITH 5-V-TOLERANT LEVEL SHIFTER

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FEATURES

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- Output Voltage Translation Tracks V_{CC}
- Supports Mixed-Mode Signal Operation on All Data I/O Ports
 - 5-V Input Down to 3.3-V Output Level Shift With 3.3-V V_{CC}
 - 5-V/3.3-V Input Down to 2.5-V Output Level Shift With 2.5-V V_{CC}
- 5-V-Tolerant I/Os With Device Powered Up or Powered Down
- Bidirectional Data Flow With Near-Zero
 Propagation Delay
- Low ON-State Resistance (r_{on}) Characteristics (r_{on} = 5 Ω Typ)
- Low Input/Output Capacitance Minimizes Loading (C_{io(OFF)} = 5 pF Typ)
- Data and Control Inputs Provide Undershoot Clamp Diodes

- Low Power Consumption (I_{CC} = 20 µA Max)
- V_{CC} Operating Range From 2.3 V to 3.6 V
- Data I/Os Support 0- to 5-V Signaling Levels (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Supports Digital Applications: Level Translation, USB Interface, Memory Interleaving, Bus Isolation
- Ideal for Low-Power Portable Equipment

DGV OR PW PACKAGE (TOP VIEW)

	•		
s [1	\cup_{16}	
1B1 [2	15] V _{CC}] <u>OE</u>
1B2 [3	14] 4B1
1A [4	13] 4B2
2B1 [5	12] 4A
2B2 [6	11] 3B1
2A [7	10] 3B2
GND [8	9] 3A
	_		,

DESCRIPTION/ORDERING INFORMATION

The SN74CB3T3257 is a high-speed TTL-compatible FET multiplexer/demultiplexer with low ON-state resistance (r_{on}), allowing for minimal propagation delay. The device fully supports mixed-mode signal operation on all data I/O ports by providing voltage translation that tracks V_{CC}. The SN74CB3T3257 supports systems using 5-V TTL, 3.3-V LVTTL, and 2.5-V CMOS switching standards, as well as user-defined switching levels (see Figure 1).

ORDERING INFORMATION

T _A	PACKA	GE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
TSSOP – PW		Tube	SN74CB3T3257PW	K0057		
–40°C to 85°C	1550P - PW	Tape and reel	SN74CB3T3257PWR	KS257		
	TVSOP – DGV	Tape and reel	SN74CB3T3257DGVR	KS257		

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

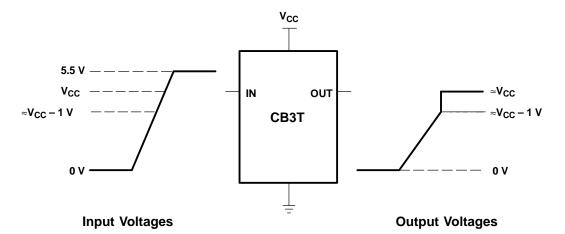
The SN74CB3T3257 is a 4-bit 1-of-2 multiplexer/demultiplexer with a single output-enable (\overline{OE}) input. The select (S) input controls the data path of the multiplexer/demultiplexer. When \overline{OE} is low, the multiplexer/demultiplexer is enabled, and the A port is connected to the B port, allowing bidirectional data flow between ports. When \overline{OE} is high, the multiplexer/demultiplexer is disabled, and a high-impedance state exists between the A and B ports.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTION TABLE (EACH MULTIPLEXER/DEMULTIPLEXER)

INPU	JTS	INPUT/OUTPUT	FUNCTION
ŌĒ	S	Α	FUNCTION
L	L	B1	A port = B1 port
L	Н	B2	A port = B2 port
н	Х	Z	Disconnect

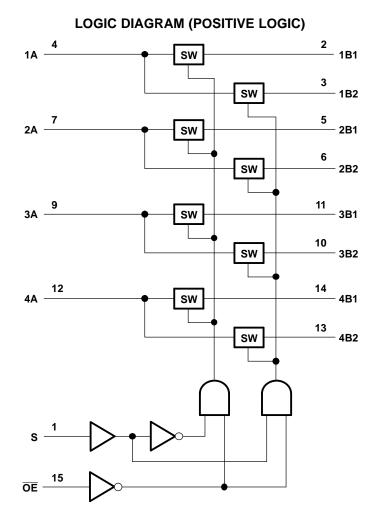


NOTE A: If the input high voltage (V_{IH}) level is greater than or equal to $V_{CC} - 1$ V, and less than or equal to 5.5 V, then the output high voltage (V_{OH}) level will be equal to approximately the V_{CC} voltage level.

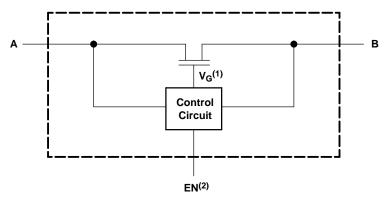




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SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



(1) Gate voltage (V_G) is equal to approximately V_{CC} + V_T when the switch is ON and $V_I > V_{CC} + V_T$.

(2) EN is the internal enable signal applied to the switch.



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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT	
V _{CC}	Supply voltage range			-0.5	7	V	
V _{IN}	/IN Control input voltage range ⁽²⁾⁽³⁾				7	V	
V _{I/O}	Switch I/O voltage range ⁽²⁾⁽³⁾⁽⁴⁾			-0.5	7	V	
I _{IK}	Control input clamp current	V _{IN} < 0			-50	mA	
I _{I/OK}	I/O port clamp current	V _{I/O} < 0			-50	mA	
I _{IO}	ON-state switch current ⁽⁵⁾				±128	mA	
	Continuous current through V_{CC} or GND				±100	mA	
0	Deckage thermal impedance (6)	DGV package			120	°C/W	
θ_{JA}	θ_{JA} Package thermal impedance ⁽⁶⁾	PW package			108	C/VV	
T _{stg}	Storage temperature range			-65	150	°C	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltages are with respect to ground, unless otherwise specified. (2)

(3)The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

 V_I and V_O are used to denote specific conditions for $V_{I/O}$. (4)

(5)

 I_{I} and I_{O} are used to denote specific conditions for $I_{I/O}$. The package thermal impedance is calculated in accordance with JESD 51-7. (6)

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2.3	3.6	V
V	High lovel control input voltage	V_{CC} = 2.3 V to 2.7 V	1.7	5.5	V
V _{IH}	High-level control input voltage	$V_{CC} = 2.7 V \text{ to } 3.6 V$	2	5.5	v
v		V_{CC} = 2.3 V to 2.7 V	0	0.7	V
V _{IL}	Low-level control input voltage $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0	0.8	v
V _{I/O}	Data input/output voltage		0	5.5	V
T _A	Operating free-air temperature		-40	85	°C

All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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Electrical Characteristics⁽¹⁾

over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST CONDIT	MIN	TYP ⁽²⁾	MAX	UNIT		
V _{IK}		$V_{CC} = 3 \text{ V}, \text{ I}_{\text{I}} = -18 \text{ mA}$				-1.2	V	
V _{OH}		See Figures 3 and 4	ee Figures 3 and 4					
I _{IN}	Control inputs	V_{CC} = 3.6 V, V_{IN} = 3.6 V to 5.5 V or GND				±10	μA	
		$V_{CC} = 3.6 V,$	$V_{I} = V_{CC} - 0.7 V \text{ to } 5.5 V$			±20		
I _I		Switch ON,	$V_{I} = 0.7 \text{ V}$ to $V_{CC} - 0.7 \text{ V}$			-40	μA	
		$V_{IN} = V_{CC}$ or GND	$V_{I} = 0$ to 0.7 V			±5		
I _{OZ} ⁽³⁾		V_{CC} = 3.6 V, V_{O} = 0 to 5.5 V, V_{I} = 0, Switch	OFF, $V_{IN} = V_{CC}$ or GND			±10	μA	
I _{off}		$V_{CC} = 0, V_{O} = 0$ to 5.5 V, $V_{I} = 0$	$= 0, V_0 = 0 \text{ to } 5.5 \text{ V}, V_1 = 0$					
I _{cc}		$V_{CC} = 3.6 \text{ V}, \text{ I}_{VO} = 0,$	$V_I = V_{CC}$ or GND			20		
		Switch ON or OFF, $V_{IN} = V_{CC}$ or GND	V ₁ = 5.5 V			20	μA	
$\Delta I_{CC}^{(4)}$	Control inputs	V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6	$_{CC}$ = 3 V to 3.6 V, One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND					
C _{in}	Control inputs	V_{CC} = 3.3 V, V_{IN} = V_{CC} or GND		3		pF		
0	A port				7			
C _{io(OFF)}	B port	V_{CC} = 3.3 V, $V_{I/O}$ = 5.5 V, 3.3 V, or GND, S	5			pF		
	A mant		V _{I/O} = 5.5 V or 3.3 V		6			
0	A port	$V_{CC} = 3.3 V,$	V _{I/O} = GND		16			
C _{io(ON)}	Durant	Switch ON, $V_{IN} = V_{CC}$ or GND $V_{IVO} = 5.5$			4		pF	
	B port		V _{I/O} = GND	16				
		$V_{CC} = 2.3 \text{ V}, \text{ TYP at } V_{CC} = 2.5 \text{ V},$	I _O = 24 mA		5	8		
(5)		$V_{I} = 0$	I _O = 16 mA		5	8	Ω	
r _{on} ⁽⁵⁾		$V_{CC} = 3 V$, $I_O = 64 mA$			5	7		
		$V_{I} = 0$	I _O = 32 mA		5 7			

 V_{IN} and I_{IN} refer to control inputs. $V_I,\,V_O,\,I_I,$ and I_O refer to data pins. All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C. (1)

(2)

(3)

For I/O ports, the parameter I_{OZ} includes the input leakage current. This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND. (4)

Measured by the voltage drop between A and B terminals at the indicated current through the switch. ON-state resistance is determined (5) by the lower of the voltages of the two (A or B) terminals.

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

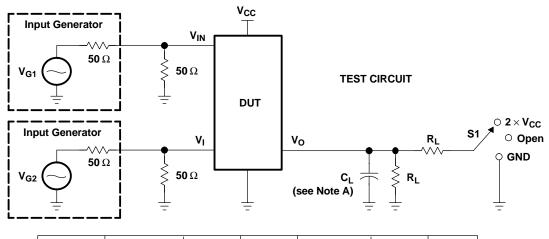
PARAMETER	FROM	TO	V _{CC} = ± 0.2	2.5 V 2 V	V _{CC} = 3.3 V ± 0.3 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	
t _{pd} ⁽¹⁾	A or B	B or A		0.15		0.25	ns
t _{pd(s)}	S	А	1	9.5	1	7	ns
	S	В	1	9	1	7.5	20
t _{en}	OE	A or B	1	9	1	7.5	ns
	S	В	1	7	1	7.5	20
t _{dis}	OE	A or B	1	6	1	8	ns

(1) The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

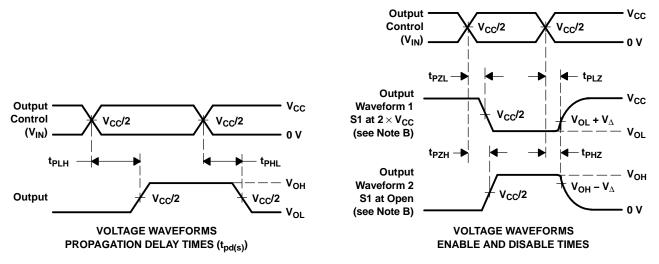


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TEST	V _{CC}	S1	RL	VI	CL	V_{Δ}
t _{pd(s)}	$\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$	Open Open	500 Ω 500 Ω	3.6 V or GND 5.5 V or GND	30 pF 50 pF	
t _{PLZ} /t _{PZL}	$\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$	$\begin{array}{c} \textbf{2} \times \textbf{V}_{\textbf{CC}} \\ \textbf{2} \times \textbf{V}_{\textbf{CC}} \end{array}$	500 Ω 500 Ω	GND GND	30 pF 50 pF	0.15 V 0.3 V
t _{PHZ} /t _{PZH}	$\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$	Open Open	500 Ω 500 Ω	3.6 V 5.5 V	30 pF 50 pF	0.15 V 0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_Q = 50 Ω , t_f \leq 2.5 ns. t_f \leq 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd(s)}. The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Test Circuit and Voltage Waveforms

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SN74CB3T3257 4-BIT 1-OF-2 FET MULTIPLEXER/DEMULTIPLEXER 2.5-V/3.3-V LOW-VOLTAGE BUS SWITCH WITH 5-V-TOLERANT LEVEL SHIFTER

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TYPICAL CHARACTERISTICS

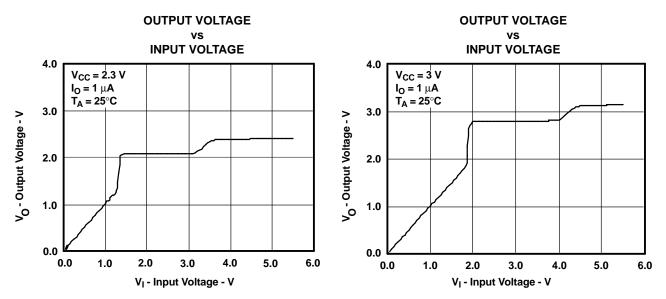
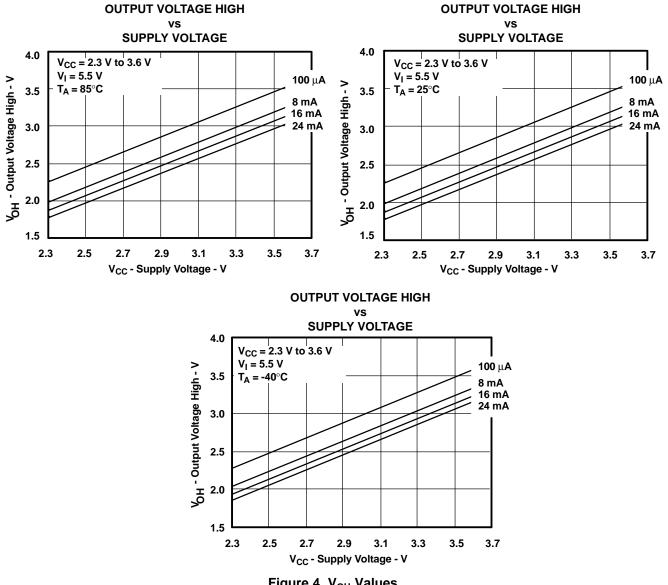


Figure 3. Data Output Voltage vs Data Input Voltage



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TYPICAL CHARACTERISTICS

Figure 4. V_{OH} Values

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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74CB3T3257DGVRE4	ACTIVE	TVSOP	DGV	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74CB3T3257DGVRG4	ACTIVE	TVSOP	DGV	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3257DGVR	ACTIVE	TVSOP	DGV	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3257PW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3257PWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3257PWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3257PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3257PWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3257PWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

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Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

Texas Instruments





TAPE AND REEL INFORMATION

TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CB3T3257DGVR	TVSOP	DGV	16	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74CB3T3257PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CB3T3257DGVR	TVSOP	DGV	16	2000	367.0	367.0	35.0
SN74CB3T3257PWR	TSSOP	PW	16	2000	367.0	367.0	35.0

MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

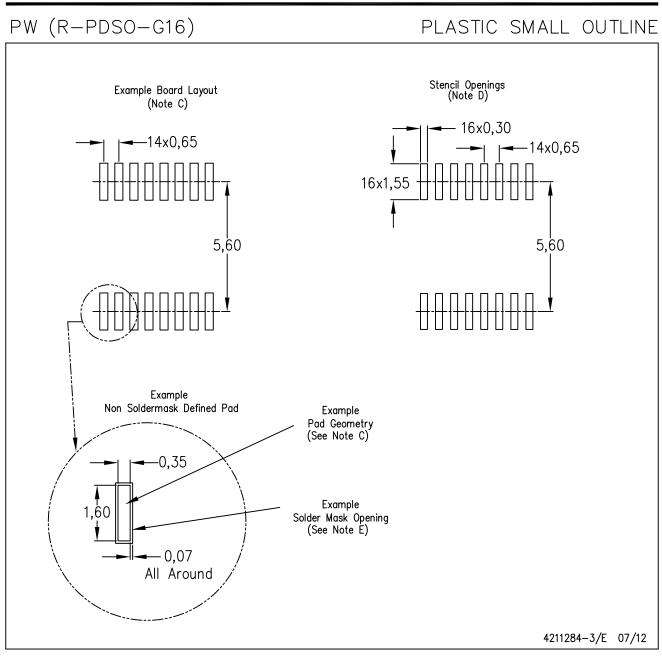
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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